SCHOTTKY BARRIER DIODE

Features

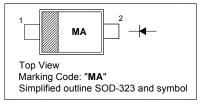
- · High reliability
- Low forward voltage and reverse current

Applications

- For electronic calculator, etc.
- · Low current rectification and high speed switching

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Absolute Maximum Ratings (T_a = 25 °C)

Parameter	Symbol	Value	Unit
Peak Reverse Voltage	V_{RM}	45	V
Reverse Voltage	V _R	10	V
Average Rectified Output Current	Io	50	mA
Peak Forward Current	I _{FM}	150	mA
Surge Forward Current	I _{surge}	500	mA
Junction Temperature	T _j	125	°C
Storage Temperature Range	T _S	- 55 to + 125	°C

Characteristics at T_a = 25 °C

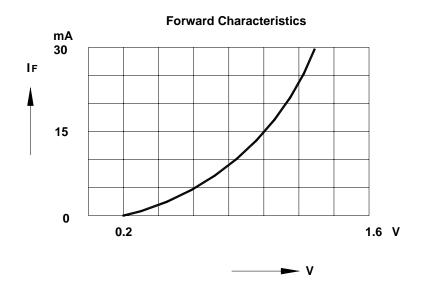
Parameter	Symbol	Min.	Max.	Unit
Forward Current at $V_F = 1 \text{ V}$	I _F	4	-	mA
Reverse Current at $V_R = 10 \text{ V}$	I _R	-	50	μΑ
Reverse Voltage at I _R = 100 µA	V_R	45	-	V
Junction Capacitance at f = 1 MHz, V = -1 V	С	-	1	pF
Rectification efficiency at Vi = 2 Vrms, R = 5 KΩ, C = 20 pF, f = 40 MHz	η	55	-	%

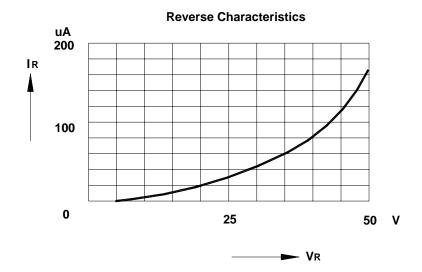






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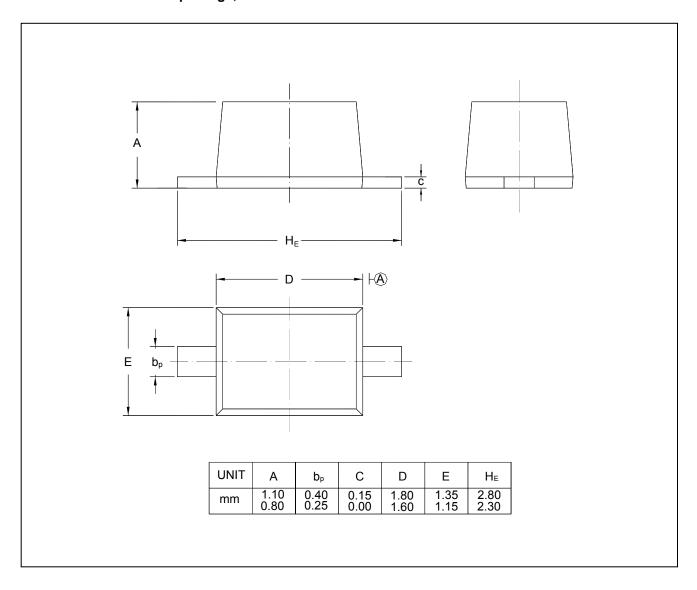




PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323





SEMTECH ELECTRONICS LTD.

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Dated: 01/09/2006